Features

- Fast Read Access Time 45 ns
- Low Power CMOS Operation

100 µA max. Standby

25 mA max. Active at 5 MHz (AT27C010L)

35 mA max. Active at 5 MHz (AT27C010)

JEDEC Standard Packages

32-Lead 600-mil PDIP

32-Lead PLCC

32-Lead TSOP

- 5V ± 10% Supply
- High Reliability CMOS Technology 2000V ESD Protection

200 mA Latchup Immunity

- Rapid[™] Programming Algorithm 100 µs/byte (typical)
- CMOS and TTL Compatible Inputs and Outputs
- Integrated Product Identification Code
- Commercial and Industrial Temperature Ranges

Description

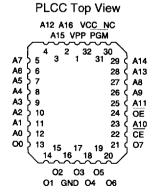
The AT27C010/L is a low-power, high performance 1,048,576 bit one-time program-mable read only memory (OTP EPROM) organized as 128K by 8 bits. They require only one 5V power supply in normal read mode operation. Any byte can be accessed in less than 45 ns, eliminating the need for speed reducing WAIT states on high performance microprocessor systems.

Two power versions are offered. In read mode, the AT27C010 typically consumes 25 mA while the AT27C010L requires only 8 mA. Standby mode supply current for both parts is typically less than 10 μ A.

(continued)

Pin Configurations

Pin Name	Function
A0 - A16	Addresses
O0 - O7	Outputs
CE	Chip Enable
OE	Output Enable
PGM	Program Strobe
NC	No Connect



PDIP Top View

			_	
		\cup		L
VPP =	1		32	□ vcc
A16 🗆	2		31	PGM
A15 🗆	3		30	□ NC
A12	4		29	□ A14
A7 =	5		28	□ A13
A6 🗆	6		27	□ A8
A7 A6 A5 A4	7		26	PGM NC A14 A13 A8 A9 A11 OE A10
A4 =	8		25	Þ A11
A3 🗆	9		24	DE OE
	10		23	Þ A10
A2 = A1 =	11		22	□ CE
AO 🗆	12		21	07
00 🗆	13		20	06
01 🗆	14		19	Þ 05
O2 🗆	15		18	07 06 05 04
GND [16		17	□ 03

TSOP Top View **Type 1**

A11		4) 1		32		þ		ŌE.
A8	A9	4	3	2	30	31	B	A10	CE
	A13	94	, "		-	29	Þ	07	-
A14		9	5	•	28		Þ		06
	NC	ቧ €	6			27	Þ	O5	
PGM		Η.	. 7	•	26		Р.		04
	VCC	귀 8	3 9	•		25	Ľ.	О3	
VPP	A16	₫ı	0 8	,	24	~~	Ħ.	~	GND
A15	AID	Ъ'		1	22	23	F.	02	^-
713	A12	₫,	2	II.	22	21	Б	00	01
A7		\Box	- 1	3	20		Б	~	AO
	A6	q 1	4	•		19	Þ	A1	AU
A5		4.	. 1	5	18		Þ		A2
	44		6 '	•		17	ь	A3	~2

1 Megabit (128K x 8) OTP CMOS EPROM

03211





Description (Continued)

The AT27C010/L in available in a choice of industry standard JEDEC-approved one-time programmable (OTP) plastic PDIP, PLCC, and TSOP packages. All devices feature two line control (CE, OE) to give designers the flexibility to prevent bus contention.

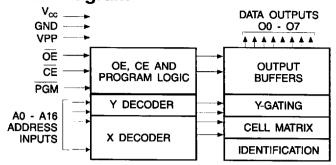
With 128K byte storage capability, the AT27C010/L allows firmware to be stored reliably and to be accessed by the system without the delays of mass storage media.

Atmel's 27C010/L have additional features to ensure high quality and efficient production use. The Rapid[™] Programming Algorithm reduces the time required to program the part and guarantees reliable programming. Programming time is typically only 100 µs/byte. The Integrated Product Identification Code electronically identifies the device and manufacturer. This feature is used by industry standard programming equipment to select the proper programming algorithms and voltages.

System Considerations

Switching between active and standby conditions via the Chip Enable pin may produce transient voltage excursions. Unless accommodated by the system design, these transients may exceed data sheet limits, resulting in device non-conformance. At a minimum, a 0.1 μ F high frequency, low inherent inductance, ceramic capacitor should be utilized for each device. This capacitor should be connected between the Vcc and Ground terminals of the device, as close to the device as possible. Additionally, to stabilize the supply voltage level on printed circuit boards with large EPROM arrays, a 4.7 μ F bulk electrolytic capacitor should be utilized, again connected between the Vcc and Ground terminals. This capacitor should be positioned as close as possible to the point where the power supply is connected to the array.

Block Diagram



Absolute Maximum Ratings*

ł	
	Temperature Under Bias55°C to +125°C
-	Storage Temperature65°C to +150°C
-	Voltage on Any Pin with Respect to Ground2.0V to +7.0V (1)
	Voltage on A9 with Respect to Ground2.0V to +14.0V (1)
	V _{PP} Supply Voltage with Respect to Ground2.0V to +14.0V ⁽¹⁾

*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: 1. Minimum voltage is -0.6V dc which may undershoot to -2.0V for pulses of less than 20 ns. Maximum output pin voltage is V_{CC} + 0.75V dc which may overshoot to +7.0V for pulses of less than 20 ns.

Operating Modes

Mode \ Pin	CE	ŌĒ	PGM	Ai	V _{PP}	Outputs
Read	V _{IL}	VIL	X ⁽¹⁾	Ai	Х	Dout
Output Disable	X	VIH	Χ	X	X	High Z
Standby	VIH	Χ	Х	X	Х	High Z
Rapid Program (2)	VIL	V _{IH}	VIL	Ai	V _{PP}	DiN
PGM Verify	VIL	VIL	ViH	Ai	V _{PP}	Dout
PGM Inhibit	V _{IH}	Х	Х	Х	V _{PP}	High Z
Product Identification (4)	VıL	V _{IL}	Х	A9 = V _H ⁽³⁾ A0 = V _I H or V _I L A1 - A16 = V _I L	Х	Identification Code

Notes: 1. X can be V_{IL} or V_{IH}.

2. Refer to Programming characteristics.

3. $V_H = 12.0 \pm 0.5 V$.

4. Two identifier bytes may be selected. All Ai inputs are held low (V_{IL}), except A9 which is set to V_H and A0 which is toggled low (V_{IL}) to select the Manufacturer's Identification byte and high (V_{IH}) to select the Device Code byte.





DC and AC Operating Conditions for Read Operation

			AT27C010 / AT27C010L									
		-45	-55	-70	-90	-12	-15					
Operating	Com.	0°C - 70°C	0°C - 70°C	0°C - 70°C	0°C - 70°C	0°C - 70°C	0°C - 70°C					
Temp. (Case)	Ind.	-40°C - 85°C	-40°C - 85°C	-40°C - 85°C	-40°C - 85°C	-40°C - 85°C	-40°C - 85°C					
Vcc Supply		5V ± 10%	5V ± 10%	5V ± 10%	5V ± 10%	5V ± 10%	5V ± 10%					

DC and Operating Characteristics for Read Operation

Symbol	Parameter	Condition		Min	Max	Units
l <u>l</u> ı	Input Load Current	V _{IN} = 0V to V _{CC}			±1	μA
ILO	Output Leakage Current	Vout = 0V to Vcc			±5	μA
l _{PP1} (2)	V _{PP} ⁽¹⁾ Read/Standby Current	V _{PP} = V _{CC}	7//4/1		10	μА
IsB	V _{CC} ⁽¹⁾ Standby Current	I _{SB1} (CMOS), $\overline{CE} = V_{CC} \pm 0.3V$			100	μΑ
130		ISB2 (TTL), $\overline{CE} = 2.0 \text{ to V}_{CC} + 0.5$	5V		1	mA
lcc	Vcc Active Current	f = 5 MHz, I _{OUT} = 0 mA,	AT27C010L		25	mA
		CE = VIL	AT27C010		35	mA
V _{IL}	Input Low Voltage			-0.6	0.8	V
ViH	Input High Voltage		•	2.0	Vcc + 0.5	V
VoL	Output Low Voltage	loL = 2.1 mA			0.4	V
VoH	Output High Voltage	loн = -400 μA		2.4		V

Notes: 1. V_{CC} must be applied simultaneously or before V_{PP}, 2. V_{PP} may be connected directly to V_{CC}, except during programand removed simultaneously or after VPP.

AC Characteristics for Read Operation

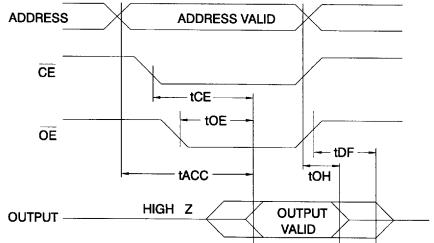
		AT27C010 / AT27C010L													
			_	45	-	55	_	70	_(90		12	-1	5	
Symbol	Parameter	Condition	Min	Max	Units										
tacc (3)	Address to Output Delay	CE = OE = V _{IL}		45		55		70		90		120		150	ns
t _{CE} ⁽²⁾	CE to Output Delay	OE = VIL		45		55		70		90		120		150	ns
toE (2, 3)	OE to Output Delay	CE = VIL		20		25		30		35		35		40	ns
t _{DF} ^(4, 5)	OE or CE High to Output Float, whicher	ver occurred first		20		20		25		25		30		35	ns
tон	Output Hold from Address, CE or OE, whichever occurred fi	irst	7		7		7		0		0		0		ns

Notes: 2, 3, 4, 5. - see AC Waveforms for Read Operation.

AT27C010/L =

ming. The supply current would then be the sum of ICC and IPP.

AC Waveforms for Read Operation (1)



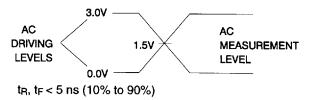
- Notes: 1. Timing measurement reference level is 1.5V for -45 and -55 devices. Input AC drive levels are $V_{IL} = 0.0V$ and $V_{IH} = 3.0V$. Timing measurement reference levels for all other speed grades are $V_{OL} = 0.8V$ and $V_{OH} = 2.0V$. Input AC drive levels are $V_{IL} = 0.45V$ and $V_{IH} = 2.4V$.
 - 2. OE may be delayed up to tce toe after the falling edge of CE without impact on tce.
- 3. OE may be delayed up to tacc toe after the address is valid without impact on tacc.
- 4. This parameter is only sampled and is not 100% tested.
- Output float is defined as the point when data is no longer driven.

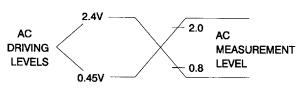
Input Test Waveforms and Measurement Levels

For -45 and -55 devices only:

For -70, -90, -12, -15,

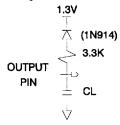
and -20 devices:





 t_R , t_F < 20 ns (10% to 90%)

Output Test Load



Note: CL = 100 pF including jig capacitance, except for the -45 and -55 devices, where CL= 30 pF.

Pin Capacitance (f = 1 MHz, T = 25° C) (1)

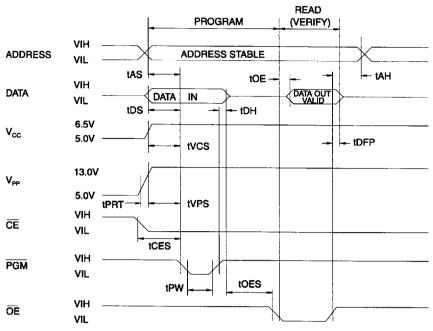
	Тур	Max	Units	Conditions
CIN	4	8	pF	V _{IN} = 0V
Cour	8	12	pF	Vout = 0V

Note: 1. Typical values for nominal supply voltage. This parameter is only sampled and is not 100% tested.





Programming Waveforms (1)



- Notes: 1. The Input Timing Reference is 0.8V for V_{IL} and 2.0V for V_{IH} .
 - 2. toe and topp are characteristics of the device but must be accommodated by the programmer.
- 3. When programming the AT27C010/L, a 0.1 μ F capacitor is required across V_{PP} and ground to suppress spurious voltage transients.

DC Programming Characteristics

 $T_A = 25 \pm 5$ °C, $V_{CC} = 6.5 \pm 0.25$ V, $V_{PP} = 13.0 \pm 0.25$ V

		Test	Li			
Symbol	Parameter	Conditions	Min Max		Units	
lu	Input Load Current	$V_{IN} = V_{IL}, V_{IH}$		±10	μА	
VIL	Input Low Level		-0.6	0.8	٧	
ViH	Input High Level		2.0	V _{CC} + 1	٧	
VoL	Output Low Voltage	l _{OL} = 2.1 mA		0.4	٧	
VoH	Output High Voltage	loн = -400 μA	2.4		٧	
lcc2	V _{CC} Supply Current (Program and Verify)			40	mA	
IPP2	Vpp Supply Current	CE = PGM = V _{IL}		20	mA	
V_{ID}	A9 Product Identification Voltage		11.5	12.5	V	

AT27C010/L

AC Programming Characteristics

 $T_A = 25 \pm 5$ °C, $V_{CC} = 6.5 \pm 0.25$ V, $V_{PP} = 13.0 \pm 0.25$ V

Sym- bol	Test Conditions* (1)	Lir Min	nits Max	Units
tas	Address Setup Time	2		μS
tces	CE Setup Time	2		μS
toes	OE Setup Time	2		μs
tos	Data Setup Time	2		μS
tAH	Address Hold Time	0		μS
tDH	Data Hold Time	2		μS
tDFP	OE High to Output Float Delay ⁽²⁾	0	130	ns
tvps	V _{PP} Setup Time	2		μS
tvcs	V _{CC} Setup Time	2		μs
tpw	PGM Program Pulse Width (3)	95	105	μS
toE	Data Valid from OE		150	ns
tPRT	VPP Pulse Rise TIme During Programming	50		ns

*AC Conditions of Test:

Input Rise and Fall Times (10% to 90%)......20 ns Input Pulse Levels......0.45V to 2.4V Input Timing Reference Level......0.8V to 2.0V Output Timing Reference Level.........0.8V to 2.0V

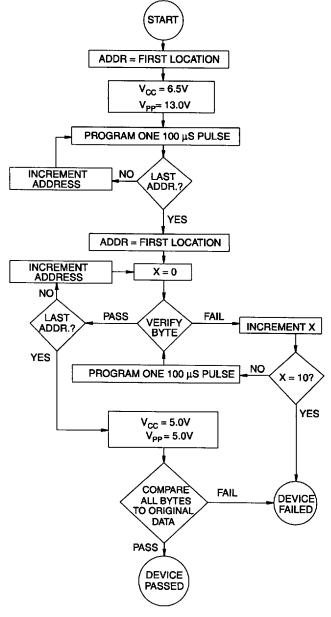
- Notes: 1. VCC must be applied simultaneously or before VPP and removed simultaneously or after VPP.
 - 2. This parameter is only sampled and is not 100% tested. Output Float is defined as the point where data is no longer driven — see timing diagram.
 - 3. Program Pulse width tolerance is 100 µsec ± 5%.

Atmel's 27C010/L Integrated **Product Identification Code**

		Pins								
Codes	A0	07	O6	O5	04	О3	O2	O 1	00	Hex Data
Manufacturer	0	0	0	0	1	1	1	1	0	1E
Device Type	1	0	0	0	0	0	1	0	1	05

Rapid Programming Algorithm

A 100 μs PGM pulse width is used to program. The address is set to the first location. Vcc is raised to 6.5V and VPP is raised to 13.0V. Each address is first programmed with one 100 μs \overline{PGM} pulse without verification. Then a verification / reprogramming loop is executed for each address. In the event a byte fails to pass verification, up to 10 successive 100 µs pulses are applied with a verification after each pulse. If the byte fails to verify after 10 pulses have been applied, the part is considered failed. After the byte verifies properly, the next address is selected until all have been checked. Vpp is then lowered to 5.0V and Vcc to 5.0V. All bytes are read again and compared with the original data to determine if the device passes or fails.







Ordering Information

t _{ACC} (ns)	Icc (mA)		Ondering O. I		
	Active	Standby	Ordering Code	Package	Operation Range
45	35	0.1	AT27C010-45JC AT27C010-45PC AT27C010-45TC	32J 32P6 32T	Commercial (0°C to 70°C)
	35	0.1	AT27C010-45JI AT27C010-45PI AT27C010-45TI	32J 32P6 32T	Industrial (-40°C to 85°C)
55	35	0.1	AT27C010-55JC AT27C010-55PC AT27C010-55TC	32J 32P6 32T	Commercial (0°C to 70°C)
	35	0.1	AT27C010-55JI AT27C010-55PI AT27C010-55TI	32J 32P6 32T	Industrial (-40°C to 85°C)
70	35	0.1	AT27C010-70JC AT27C010-70PC AT27C010-70TC	32J 32P6 32T	Commercial (0°C to 70°C)
	35	0.1	AT27C010-70JI AT27C010-70PI AT27C010-70TI	32J 32P6 32T	Industrial (-40°C to 85°C)
90	35	0.1	AT27C010-90JC AT27C010-90PC AT27C010-90TC	32J 32P6 32T	Commercial (0°C to 70°C)
	35	0.1	AT27C010-90JI AT27C010-90PI AT27C010-90TI	32J 32P6 32T	Industrial (-40°C to 85°C)
120	35	0.1	AT27C010-12JC AT27C010-12PC AT27C010-12TC	32J 32P6 32T	Commercial (0°C to 70°C)
	35	0.1	AT27C010-12JI AT27C010-12PI AT27C010-12TI	32J 32P6 32T	Industrial (-40°C to 85°C)
150	35	0.1	AT27C010-15JC AT27C010-15PC AT27C010-15TC	32J 32P6 32T	Commercial (0°C to 70°C)
	35	0.1	AT27C010-15JI AT27C010-15PI AT27C010-15TI	32J 32P6 32T	Industrial (-40°C to 85°C)

Ordering Information

tacc (ns)	Icc (mA)				
	Active	Standby	Ordering Code	Package	Operation Range
45	25	0.1	AT27C010L-45JC AT27C010L-45PC AT27C010L-45TC	32J 32P6 32T	Commercial (0°C to 70°C)
	25	0.1	AT27C010L-45JI AT27C010L-45PI AT27C010L-45TI	32J 32P6 32T	Industrial (-40°C to 85°C)
55	25	0.1	AT27C010L-55JC AT27C010L-55PC AT27C010L-55TC	32J 32P6 32T	Commercial (0°C to 70°C)
	25	0.1	AT27C010L-55JI AT27C010L-55PI AT27C010L-55TI	32J 32P6 32T	Industrial (-40°C to 85°C)
70	25	0.1	AT27C010L-70JC AT27C010L-70PC AT27C010L-70TC	32J 32P6 32T	Commercial (0°C to 70°C)
	25	0.1	AT27C010L-70JI AT27C010L-70PI AT27C010L-70TI	32J 32P6 32T	Industrial (-40°C to 85°C)
90	25	0.1	AT27C010L-90JC AT27C010L-90PC AT27C010L-90TC	32J 32P6 32T	Commercial (0°C to 70°C)
	25	0.1	AT27C010L-90JI AT27C010L-90PI AT27C010L-90TI	32J 32P6 32T	Industrial (-40°C to 85°C)
120	25	0.1	AT27C010L-12JC AT27C010L-12PC AT27C010L-12TC	32J 32P6 32T	Commercia (0°C to 70°C)
	25	0.1	AT27C010L-12JI AT27C010L-12PI AT27C010L-12TI	32J 32P6 32T	Industrial (-40°C to 85°C)
150	25	0.1	AT27C010L-15JC AT27C010L-15PC AT27C010L-15TC	32J 32P6 32T	Commercial (0°C to 70°C)
	25	0.1	AT27C010L-15JI AT27C010L-15PI AT27C010L-15TI	32J 32P6 32T	Industrial (-40°C to 85°C)

Package Type				
32J	32 Lead, Plastic J-Leaded Chip Carrier (PLCC)			
32P6	32 Lead, 0.600" Wide, Plastic Dual Inline Package (PDIP)			
32T	32 Lead, Plastic Thin Small Outline Package (TSOP)			

